



Information Society
Technologies

Emerging Nanoelectronics

Preparing FP7

1 February 2005

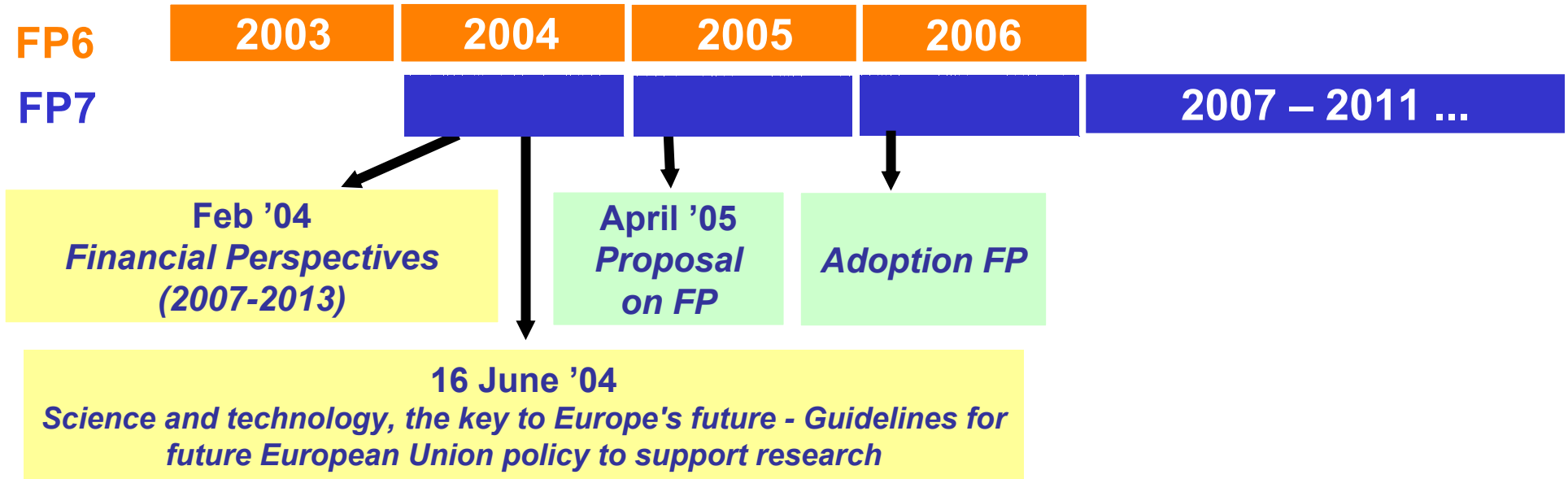
Patrick Van Hove

*Future and Emerging Technologies
DG Information Society & Media
European Commission*





Preparing FP7: The Roadmap and the 6+2 Axes



FP7: 6+2 axes

- *Collaborative Research*
- *European Technological Initiatives*
- *ERC: Basic Research Grants for individual research teams*
- An attractive Europe for best Researchers
- *Research Infrastructures*
- Co-ordination of national research programmes
- +
- Space (ESA)
- Security



■ IST in FP7

- ERC & Basic Technology Research in ICTs → Options Paper
- Collaborative RTD:
 - *ISTAG (Working Group on Grand Challenges)*
 - *Strategic Orientations*
 - *FP7 Workshops:*
 - 21-22 Apr 04: FET FP7 Workshop
 - 12 Oct 04: ICT at the crossroads with Life Sciences
 - 8-9 Nov 04: Robotic Systems for extending Human Capabilities
 - 16 Dec 04: Emerging Nanoelectronics
- European Technology Platforms
 - *Developments of ENIAC platform*
 - *Agenda 2020*



Emerging Nanoelectronics: Preparing for FP7



Overall FP7 Workshop, Brussels, 21-22 April 2004

- **Components**
- **Systems**
- **Intelligence**

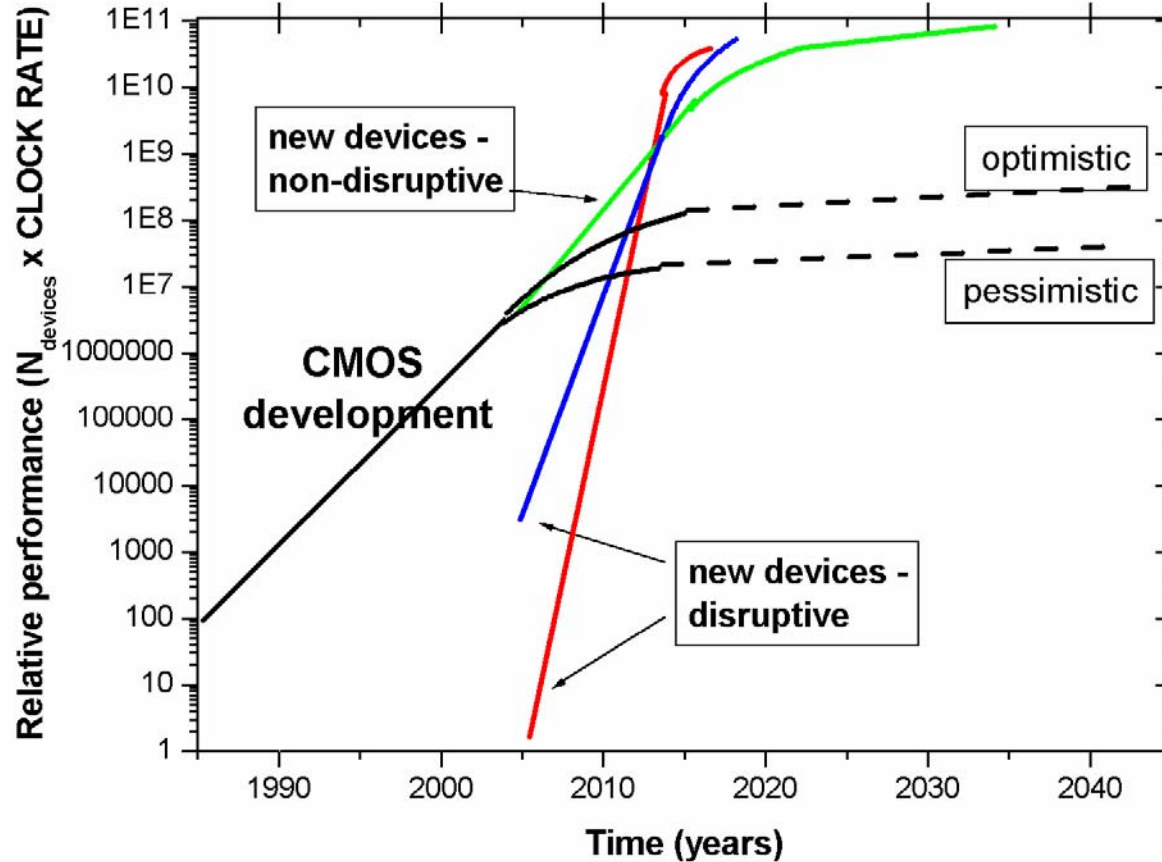
**Emerging Nanoelectronics Workshop,
Brussels, 16 December 2004**

- **Draft Report now available: see
<http://www.cordis.lu/ist/fet/nid.htm>**
- **PLEASE SEND US YOUR COMMENTS/INPUTS**



Why Emerging Nano R&D?

1. Limits of logic scaling



Source: Michael Forshaw, University College London

- CMOS: Limits of scaling & limits of benefits of scaling: frequency increase, power scaling, delays, etc.



ITRS ERD: Logic



- **Non-conventional CMOS:**
pursuing the shrinking until the “16 nm node” in 2019?
- **Charge-transport based emerging devices:**
Nanotubes, Nanowires, Tunnelling devices, etc.
- **Breakthrough devices:**
Quantum, spin-based, molecular, etc.



ERD: Logic: Limiting Factors



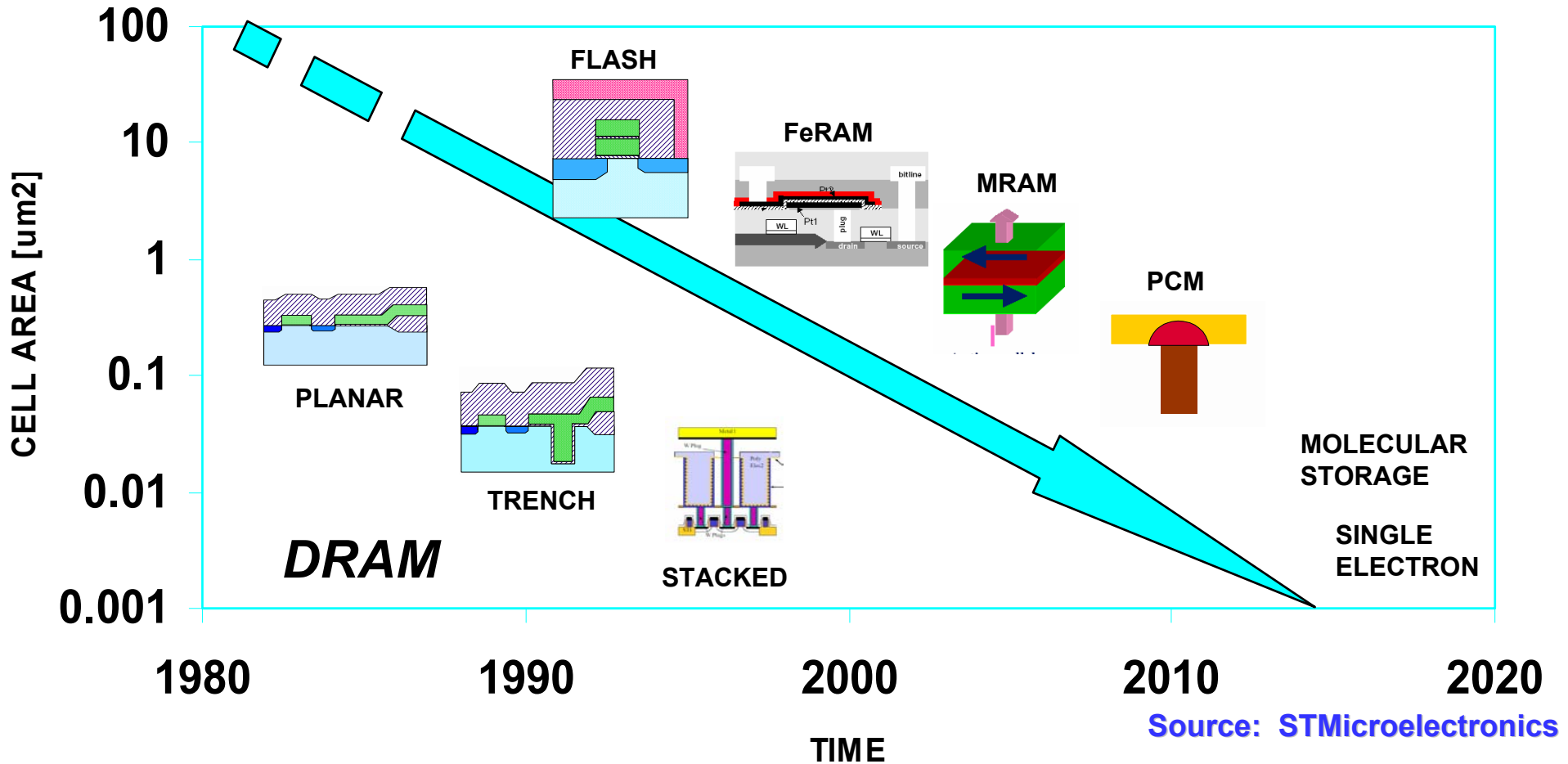
Aim: Improve logic performance, density, cost, power

- **Power dissipation density**
- **Tunnelling effects**
- **Discreteness of matter/dopants**
- **Limits of energy/device vs. thermal noise**
- **Beyond single devices: interconnections, etc.**
- **Patterning - manufacturing accuracy**
- **Yield**
- **Etc.**



Why Emerging Nano R&D?

2. Limits of memory scaling



■ ...and looking for solid-state non-volatile storage



ERD: Memories: Targets



Aim: Improve density, cost, retention time, write time & energy

- **Limits to scaling of charge-based devices?**
- **More open to alternative approaches?**
- **In development: FRAM, MRAM, PCRAM**
- **New approaches: MIM, molecular, single/few e-, etc.**
- **Manufacturing issues**
- **Yield, Fault tolerance**

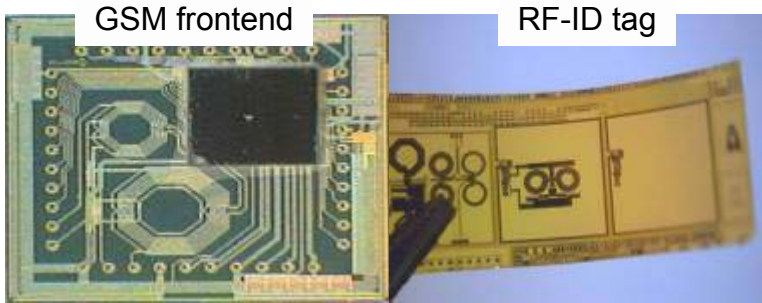


Why Emerging Nano R&D?

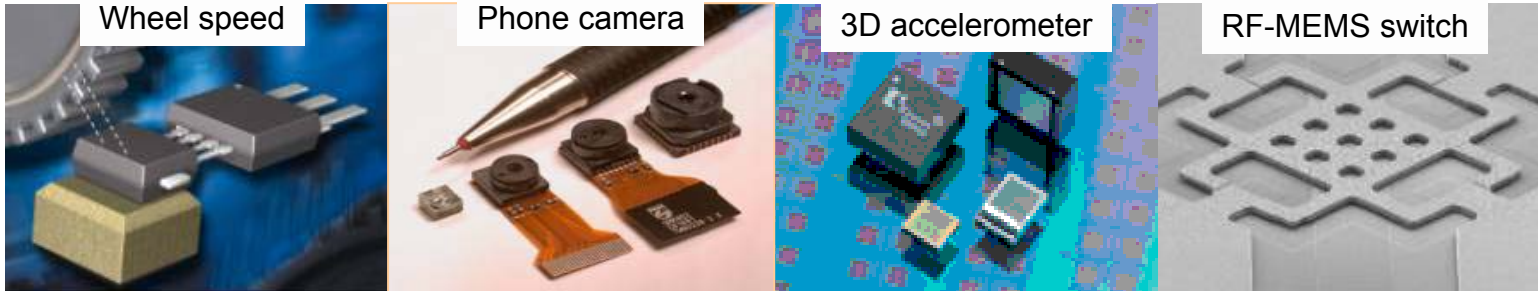
3. Value-added functions



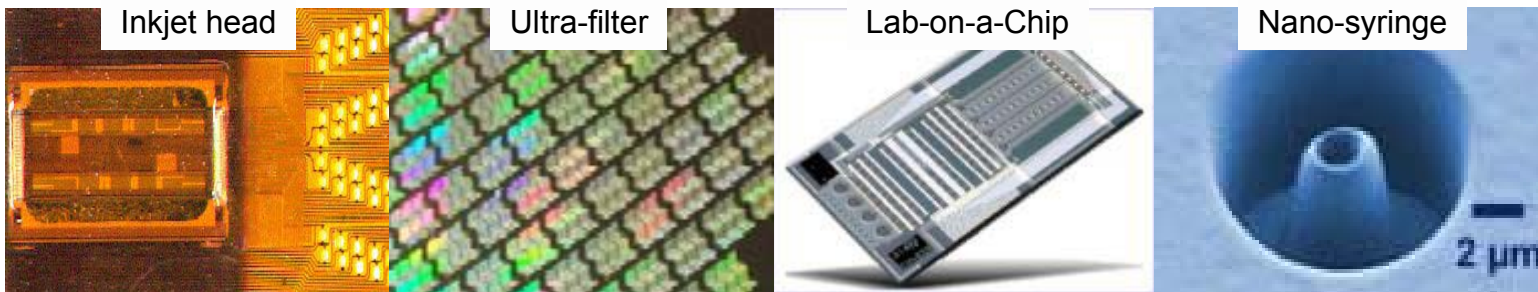
integrated passives



sensors actuators



fluidics



Source: Philips

- Intelligent Systems that compute and interact



Towards a Research Programme: Topics



- **Multidisciplinary Vision-driven Research**
 - Materials, Devices, Circuits, Architectures
 - Experimental fabrication & characterisation
 - Design - Modelling
 - Path towards mass-manufacturing~

- **Curiosity-driven research**
 - Science and technology
 - Not too many constraints



Towards a Research Programme: Organisation



- **Collaborative Multidisciplinary Research**
 - Development of concepts
 - Answering elementary limitations
 - Patenting
- **Curiosity-driven research**
 - New concepts – Proof of concept
- **Access to Infrastructure**
 - Needs to be managed & funded
 - Expect to become specialised
- **Roadmap: New impetus?**
- **Link with ENIAC**



Towards a Research Programme: Participants



- **Majority expected from Academic and Research**
- **Role of industry**
 - Research participant
 - Advise, assessment
- **Mobility of researchers**
 - Among partners in projects
 - “European single market” for researchers
- **Synergy among various lines of action. Conference**
- **Integration of New Member States**
 - Better awareness of potential
- **International Cooperation**



Information Society
Technologies

Emerging Nanoelectronics: Preparing for FP7



Emerging Nanoelectronics Workshop,
Brussels, 16 December 2004

- Draft Report now available: see <http://www.cordis.lu/ist/fet/nid.htm>
- PLEASE SEND US YOUR COMMENTS/INPUTS



Information Society
Technologies

Additional Slides





ITRS ERD Memory Devices



- Phase change memory
- Floating body DRAM
- Nano floating gate memory
- Single/few electron memory
- Insulator resistance change memory
- Molecular memories



ITRS ERD Logic devices



- RSFQ
- Carbon Nanotubes
- Nanowire structures
- Crossbar structures
- Resonant tunnelling devices
- Single electron transistors
- Molecular devices
- Quantum cellular automata
- Spin transistors



ITRS ERD Architectures



- **Quantum Cellular Automata Architecture**
- **Cellular nonlinear networks**
- **Fault-tolerant architectures**
- **Biologically-inspired architectures**
- **Coherent quantum computing**



■ Material synthesis

- Molecular synthesis
- Thin film synthesis
- Nanostructure synthesis
- Self and directed assembly
- Material interface, contacts

■ Characterisation

- Characterisation of chemical, structural, impurity, defect, electronic information with nanometer or even atomic scale
- Characterisation of state properties

■ Modelling and simulation